

Document Number: MHW9182CN Rev. 4, 10/2006

**√RoHS** 

# **CATV Amplifier Module**

## Features

- Specified for 110- and 152-Channel Loading
- **Excellent Distortion Performance** •
- Superior Gain, Return Loss and DC Current Stability over Temperature •
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions •

## Applications

- CATV Systems Operating in the 40 to 1000 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk • **Distribution Amplifiers for CATV Systems**
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation • Description

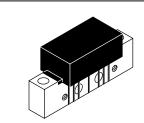
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- 24 Vdc Supply, 40 to 1000 MHz, CATV Forward Amplifier Module
- Replaced MHW9182C. There are no form, fit or function changes with this part replacement.
- **RoHS** Compliant

## **MHW9182CN**

1000 MHz 19.4 dB GAIN 152-CHANNEL **CATV AMPLIFIER MODULE** 



CASE 1302-01, STYLE 1

## Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+70	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	-20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C

Table 2. Electrical Characteristics (V<sub>CC</sub> = 24 Vdc,  $T_C$  = +30°C, 75  $\Omega$  system unless otherwise noted)

Characte	Symbol	Min	Тур	Max	Unit	
Frequency Range		BW	40	_	1000	MHz
Power Gain	50 MHz 1000 MHz	G <sub>p</sub>	18 18.7	18.5 19.4	19 20.7	dB
Slope	40 - 1000 MHz	S	0.4	0.9	1.4	dB
Gain Flatness (40 - 1000 MHz, Peak to Valley)		G <sub>F</sub>	_	0.4	0.8	dB
Return Loss — Input/Output (Z <sub>o</sub> =	75 Ohms) @ 40 MHz @ f > 40 MHz (Derate)	IRL/ORL	20 —		0.006	dB dB/MHz
Composite Second Order (V <sub>out</sub> = +40 dBmV/ch., Worst Ca (V <sub>out</sub> = +38 dBmV/ch., Worst Ca		CSO <sub>110</sub> CSO <sub>152</sub>		-70 -69	- 63 - 63	dBc





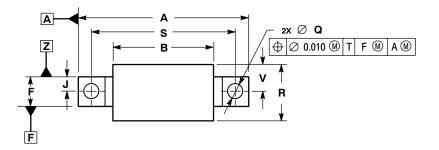
Characteristic	Symbol	Min	Тур	Max	Unit	
Cross Modulation Distortion @ Ch 2						dBc
(V <sub>out</sub> = +40 dBmV/ch., FM = 55 MHz)	110-Channel FLAT	XMD <sub>110</sub>	_	-66	- 64	
$(V_{out} = +38 \text{ dBmV/ch.}, \text{FM} = 55 \text{ MHz})$	152-Channel FLAT	XMD <sub>152</sub>	—	-65	- 61	
Composite Triple Beat						dBc
(V <sub>out</sub> = +40 dBmV/ch., Worst Case)	110-Channel FLAT	CTB <sub>110</sub>		-68	- 66	
(V <sub>out</sub> = +38 dBmV/ch., Worst Case)	152-Channel FLAT	CTB <sub>152</sub>	—	-64	- 61	
Noise Figure	50 MHz	NF	_	4.0	5.0	dB
-	550 MHz		—	4.5	—	
	860 MHz		—	5.5	—	
	1000 MHz		—	6.0	7.5	
DC Current (V <sub>DC</sub> = 24 V, T <sub>C</sub> = 30°C)		I <sub>DC</sub>	180	210	240	mA

**Table 2. Electrical Characteristics** ( $V_{CC}$  = 24 Vdc,  $T_C$  = +30°C, 75  $\Omega$  system unless otherwise noted) (continued)

## MHW9182CN



## **PACKAGE DIMENSIONS**

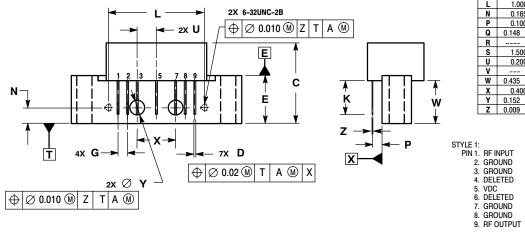


NOTES:

CONTROLLING DIMENSION: INCH.
 INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α		1.775		45.085		
В		1.085		27.559		
C		0.840		21.336		
D	0.015	0.021	0.381	0.533		
Ε	0.465	0.510	11.811	12.954		
F	0.300	0.325	7.620	8.255		
G	0.100	BSC	2.540 BSC			
J	0.156 BSC 3.96		3.962	2 BSC		
K	0.315	0.355	8.001	9.017		
L	1.000	BSC	25.400 BSC			
N	0.165 BSC		4.191	4.191 BSC		
Ρ	0.100 BSC		2.540	BSC		
Q	0.148	0.168	3.759	4.267		
R		0.600		15.240		
S	1.500 BSC		38.10	0 BSC		
U	0.200 BSC		5.080	0 BSC		
۷		0.250		6.350		
W	0.435		11.049			
X	0.400 BSC		10.160 BSC			
Y	0.152	0.163	3.861	4.140		
Z	0.009	0.011	0.229	0.279		

**ARCHIVE INFORMATION** 



CASE 1302-01 **ISSUE E** 



## **REVISION HISTORY**

The following table summarizes revisions to this document.

Revision	Date	Description	
4	Oct. 2006	<ul> <li>Added missing minus sign to CSO<sub>110</sub> Typ value, p. 1</li> </ul>	

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#### How to Reach Us:

#### Home Page: www.freescale.com

E-mail:

support@freescale.com

#### USA/Europe or Locations Not Listed:

Freescale Semiconductor. Inc. Technical Information Center, EL516 2100 East Elliot Road Tempe, Arizona 85284 +1-800-521-6274 or +1-480-768-2130 www.freescale.com/support

#### Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) www.freescale.com/support

#### Japan:

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Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

#### Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd. Technical Information Center 2 Dai King Street Tai Po Industrial Estate Tai Po, N.T., Hong Kong +800 2666 8080 support.asia@freescale.com

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